NL17SG125

Bus Buffer with 3-State Output

The NL17SG125 MiniGate™ is an advanced high−speed CMOS Bus Buffer with 3−State Output in ultra−small footprint.

The NL17SG125 input structures provides protection when voltages up to 4.6 V are applied.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: t_{PD} = 2.4 ns (Typ) at V_{CC} = 3.0 V, C_L = 15 pF
- Low Power Dissipation: I_{CC} = 0.5 μA (Max) at T_A = 25°C
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra−Small Packages
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

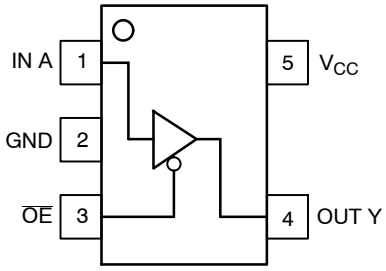


Figure 1. SOT−953
(Top Thru View)

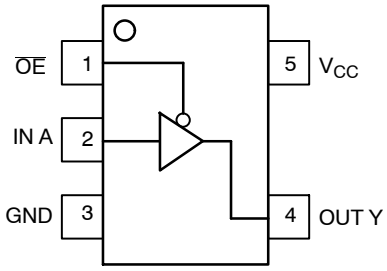


Figure 2. SC−88A
(Top View)

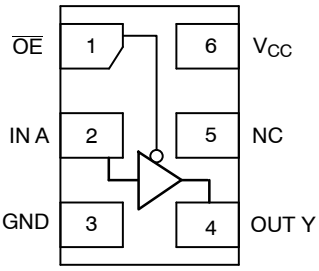


Figure 3. UDFN6
(Top View)

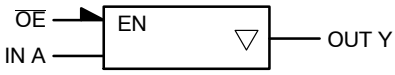


Figure 4. Logic Symbol

PIN ASSIGNMENT

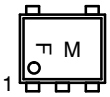
Pin Number	SOT−953	SC−88A	UDFN6
1	IN A	$\overline{OE}$	$\overline{OE}$
2	GND	IN A	IN A
3	$\overline{OE}$	GND	GND
4	OUT Y	OUT Y	OUT Y
5	V_{CC}	V_{CC}	NC
6			V_{CC}

ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS

SOT−953
CASE 527AE

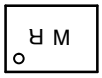


F = Specific Device Code
(F with 90 degree clockwise rotation)
M = Month Code

UDFN6
1.0 x 1.0
CASE 517BX

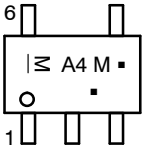
K = Specific Device Code
(K with 270 degree clockwise rotation)
M = Month Code

UDFN6
1.45 x 1.0
CASE 517AQ



R = Specific Device Code
(R with 180 degree clockwise rotation)
M = Month Code

SC−88A
DF SUFFIX
CASE 419A



A4 = Device Code
M = Date Code*
▪ = Pb−Free Package

(Note: Microdot may be in either location)
*Date Code orientation and/or position may vary depending upon manufacturing location.

FUNCTION TABLE

A Input	$\overline{OE}$ Input	Y Output
L	L	L
H	L	H
X	H	Z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		−0.5 to +5.5	V
V_{IN}	DC Input Voltage		−0.5 to +4.6	V
V_{OUT}	DC Output Voltage	Output at High or Low State Power−Down Mode (V_{CC} = 0 V)	−0.5 to V_{CC} +0.5 −0.5 to +4.6	V
I_{IK}	DC Input Diode Current	V_{IN} < GND	−20	mA
I_{OK}	DC Output Diode Current	V_{OUT} < GND	−20	mA
I_{OUT}	DC Output Source/Sink Current		±20	mA
I_{CC}	DC Supply Current per Supply Pin		±20	mA
I_{GND}	DC Ground Current per Ground Pin		±20	mA
T_{STG}	Storage Temperature Range		−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		+150	°C
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V−0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3)	>2000 >100	V
$I_{LATCHUP}$	Latchup Performance	Above V_{CC} and Below GND at 125°C (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm−by−1 inch, 2−ounce copper trace with no air flow.
2. Tested to EIA/JESD22−A114−A.
3. Tested to EIA/JESD22−A115−A.
4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics		Min	Max	Unit
V_{CC}	Positive DC Supply Voltage		0.9	3.6	V
V_{IN}	Digital Input Voltage		0.0	3.6	V
V_{OUT}	Output Voltage	Output at High or Low State Power−Down Mode (V_{CC} = 0 V)	0.0 0.0	V_{CC} 3.6	V
T_A	Operating Temperature Range		−55	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fail Rate	V_{CC} = 3.3 V ± 0.3 V	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions		V_{CC} (V)	T_A = 25°C		T_A = -55°C to +125°C		Unit
					Min	Max	Min	Max	
V_{IH}	High-Level Input Voltage			0.9	V_{CC}		V_{CC}		V
				1.1 to 1.3	0.7xV_{CC}		0.7xV_{CC}		
				1.4 to 1.6	0.65xV_{CC}		0.65xV_{CC}		
				1.65 to 1.95	0.65xV_{CC}		0.65xV_{CC}		
				2.3 to 2.7	1.7		1.7		
				3.0 to 3.6	2.0		2.0		
V_{IL}	Low-Level Input Voltage			0.9		GND		GND	V
				1.1 to 1.3		0.3xV_{CC}		0.3xV_{CC}	
				1.4 to 1.6		0.35xV_{CC}		0.35xV_{CC}	
				1.65 to 1.95		0.35xV_{CC}		0.35xV_{CC}	
				2.3 to 2.7		0.7		0.7	
				3.0 to 3.6		0.8		0.8	
V_{OH}	High-Level Output Voltage	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −20 μA	0.9	0.75		0.75		V
			I_{OH} = -0.3 mA	1.1 to 1.3	0.75xV_{CC}		0.75xV_{CC}		
			I_{OH} = -1.7 mA	1.4 to 1.6	0.75xV_{CC}		0.75xV_{CC}		
			I_{OH} = -3.0 mA	1.65 to 1.95	Vcc-0.45		Vcc-0.45		
			I_{OH} = -4.0 mA	2.3 to 2.7	2.0		2.0		
			I_{OH} = -8.0 mA	3.0 to 3.6	2.48		2.48		
V_{OL}	Low-Level Output Voltage	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20 μA	0.9		0.1		0.1	V
			I_{OL} = 0.3 mA	1.1 to 1.3		0.25xV_{CC}		0.25xV_{CC}	
			I_{OL} = 1.7 mA	1.4 to 1.6		0.25xV_{CC}		0.25xV_{CC}	
			I_{OL} = 3.0 mA	1.65 to 1.95		0.45		0.45	
			I_{OL} = 4.0 mA	2.3 to 2.7		0.4		0.4	
			I_{OL} = 8.0 mA	3.0 to 3.6		0.4		0.4	
I_{IN}	Input Leakage Current	0 ≤ V_{IN} ≤ 3.6 V		0 to 3.6		±0.1		±1.0	μA
I_{CC}	Quiescent Supply Current	V_{IN} = V_{CC} or GND		3.6		1.0		10.0	μA
I_{OZ}	3−State Output Leakage Current	V_{IN} = V_{IH} or V_{IL} V_{OUT} = 0 to 3.6 V		0.9 to 3.6		1.0		10.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

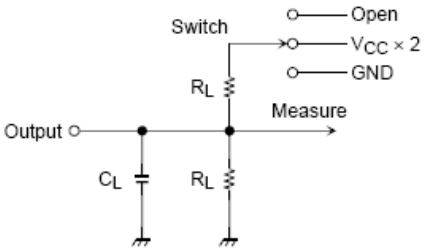
Symbol	Parameter	Test Condition	V_{CC} (V)	T_A = 25 °C			T_A = -55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay, A to Y	C_L = 10 pF, R_L = 1 MΩ	0.9	-	11.3	13.6	-	15.9	ns
			1.1 to 1.3	-	8.3	10.4	-	12.8	
			1.4 to 1.6	-	5.0	8.5	-	10.0	
			1.65 to 1.95	-	4.0	6.2	-	6.7	
			2.3 to 2.7	-	2.6	3.9	-	4.4	
			3.0 to 3.6	-	2.1	3.1	-	3.7	
		C_L = 15 pF, R_L = 1 MΩ	0.9	-	12.6	14.7	-	17.0	ns
			1.1 to 1.3	-	9.6	11.5	-	15.2	
			1.4 to 1.6	-	5.6	9.3	-	11.2	
			1.65 to 1.95	-	4.5	6.9	-	7.1	
			2.3 to 2.7	-	2.9	4.4	-	5.0	
			3.0 to 3.6	-	2.4	3.4	-	3.9	
		C_L = 30 pF, R_L = 1 MΩ	0.9	-	14.5	16.3	-	19.6	ns
			1.1 to 1.3	-	11.3	13.6	-	17.5	
			1.4 to 1.6	-	8.2	13.1	-	15.9	
			1.65 to 1.95	-	6	9.2	-	9.6	
			2.3 to 2.7	-	4	5.7	-	6.1	
			3.0 to 3.6	-	3.3	4.4	-	4.8	
t_{PZH}, t_{PZL}	Output Enable Time, $\overline{OE}$ to Y	C_L = 10 pF;							ns
		R_L = 100 kΩ	0.9	-	11.0	13.3	-	15.8	
		R_L = 5 kΩ	1.1 to 1.3	-	8.4	10.9	-	13.0	
		R_L = 5 kΩ	1.4 to 1.6	-	5.3	7.8	-	8.3	
		R_L = 5 kΩ	1.65 to 1.95	-	3.9	5.5	-	5.9	
		R_L = 5 kΩ	2.3 to 2.7	-	2.5	3.5	-	3.8	
		R_L = 5 kΩ	3.0 to 3.6	-	2.1	2.7	-	3	
		C_L = 15 pF;							ns
		R_L = 100 kΩ	0.9	-	12.0	14.8	-	17.0	
		R_L = 5 kΩ	1.1 to 1.3	-	9.0	11.7	-	13.8	
		R_L = 5 kΩ	1.4 to 1.6	-	5.9	8.9	-	11	
		R_L = 5 kΩ	1.65 to 1.95	-	4.4	6.3	-	6.5	
		R_L = 5 kΩ	2.3 to 2.7	-	2.9	3.9	-	4.2	
		R_L = 5 kΩ	3.0 to 3.6	-	2.3	3	-	3.3	
		C_L = 30 pF;							ns
		R_L = 100 kΩ	0.9	-	13.0	15.2	-	18.3	
		R_L = 5 kΩ	1.1 to 1.3	-	10.0	13.1	-	15.2	
		R_L = 5 kΩ	1.4 to 1.6	-	8.3	12.2	-	13.7	
		R_L = 5 kΩ	1.65 to 1.95	-	6.1	8.6	-	9.7	
		R_L = 5 kΩ	2.3 to 2.7	-	3.8	5	-	5.5	
		R_L = 5 kΩ	3.0 to 3.6	-	2.9	3.8	-	4.2	

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns) (continued)

Symbol	Parameter	Test Condition	V_{CC} (V)	T_A = 25 °C			T_A = -55°C to +125°C		Unit
				Min	Typ	Max	Min	Max	
t_{PHZ}, t_{PLZ}	Output Disable Time, $\overline{OE}$ to Y	C_L = 10 pF;							ns
		R_L = 100 kΩ	0.9	-	100.4	-	-	-	
		R_L = 5 kΩ	1.1 to 1.3	-	9.1	14.4	-	22.4	
		R_L = 5 kΩ	1.4 to 1.6	-	7.1	9.1	-	10.4	
		R_L = 5 kΩ	1.65 to 1.95	-	6.5	8.3	-	9	
		R_L = 5 kΩ	2.3 to 2.7	-	5.8	7.3	-	8.8	
		R_L = 5 kΩ	3.0 to 3.6	-	5.4	6.9	-	7.6	
		C_L = 15 pF;							ns
		R_L = 100 kΩ	0.9	-	122.2	-	-	-	
		R_L = 5 kΩ	1.1 to 1.3	-	9.8	15.3	-	25.1	
		R_L = 5 kΩ	1.4 to 1.6	-	7.8	9.8	-	11.3	
		R_L = 5 kΩ	1.65 to 1.95	-	7.2	9.2	-	10.6	
		R_L = 5 kΩ	2.3 to 2.7	-	7	8.2	-	10.3	
		R_L = 5 kΩ	3.0 to 3.6	-	6.6	7.7	-	9.5	
		C_L = 30 pF;							ns
		R_L = 100 kΩ	0.9	-	217.1	-	-	-	
		R_L = 5 kΩ	1.1 to 1.3	-	13.2	19.6	-	31.9	
		R_L = 5 kΩ	1.4 to 1.6	-	12.2	13.5	-	14.9	
		R_L = 5 kΩ	1.65 to 1.95	-	11.4	12.7	-	13.9	
		R_L = 5 kΩ	2.3 to 2.7	-	11.3	12.2	-	13.5	
		R_L = 5 kΩ	3.0 to 3.6	-	10.2	11.5	-	12.9	
C_{IN}	Input Capacitance		0 to 3.6		3	-	-	-	pF
C_O	Output Capacitance	V_O = GND	0		3	-	-	-	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz	0.9 to 3.6	-	4	-	-	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no−load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.



Characteristics	Switch
t_{pLH}, t_{pHL}	Open
t_{pLZ}, t_{pZL}	V_{CC} × 2
t_{pHZ}, t_{pZH}	GND

Figure 5. Test Circuit

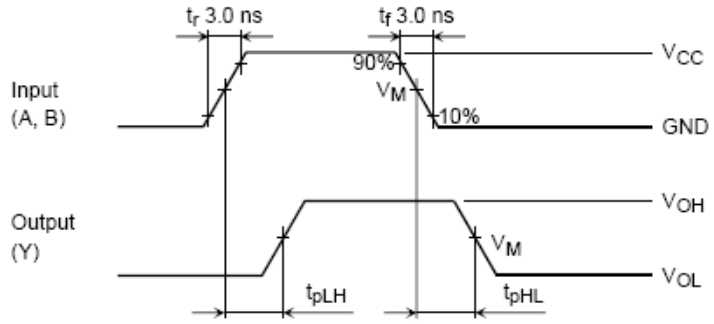


Figure 6. t_{PLH}, t_{PHL} Waveforms

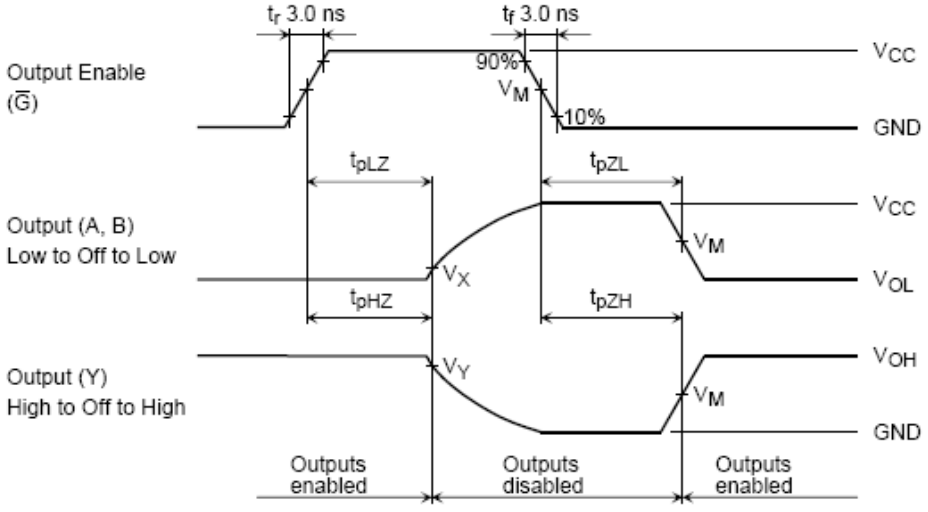


Figure 7. t_{PLZ}, t_{PHZ}, t_{PZH}, t_{PZL} Waveforms

ORDERING INFORMATION

Device	Package	Shipping†
NL17SG125P5T5G	SOT−953 (Pb−Free)	8000 / Tape & Reel
NL17SG125DFT2G	SC−88A (Pb−Free)	3000 / Tape & Reel
NLV17SG125DFT2G*	SC−88A (Pb−Free)	3000 / Tape & Reel
NL17SG125MU1TCG**	UDFN6 1.45 x 1 mm (Pb−Free)	3000 / Tape & Reel
NL17SG125MU3TCG**	UDFN6 1 x 1 mm (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

**In Development

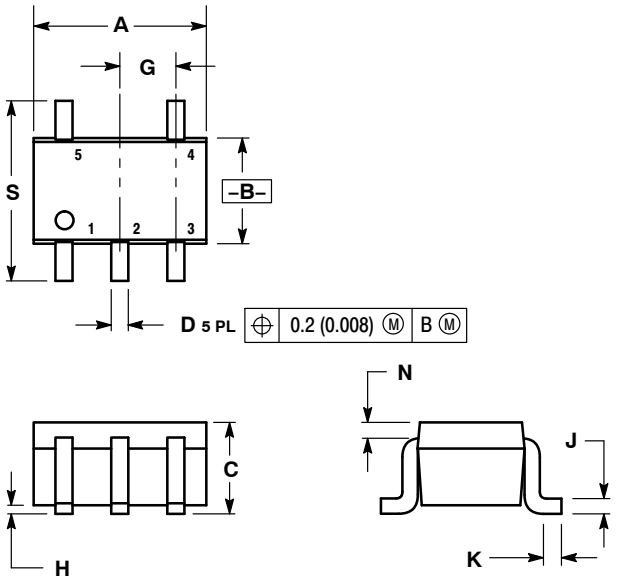
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

SC−88A (SC−70−5/SOT−353)
CASE 419A−02
ISSUE L

SCALE 2:1

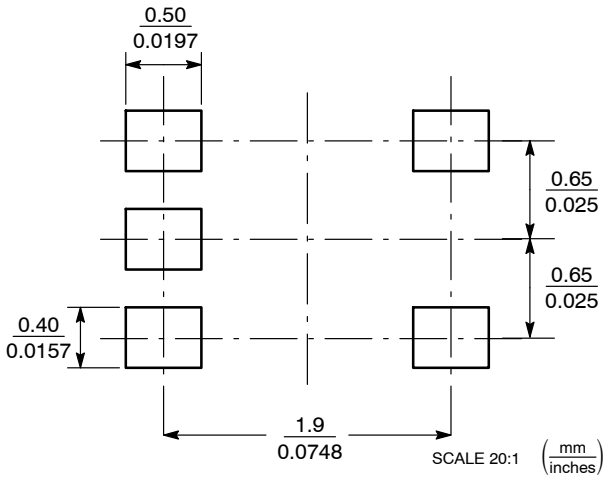
DATE 17 JAN 2013



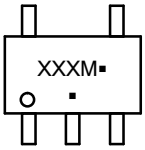
NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A−01 OBSOLETE. NEW STANDARD 419A−02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

SOLDER FOOTPRINT



GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 3:
PIN 1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE 1

STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 5:
PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

STYLE 6:
PIN 1. EMITTER 2
2. BASE 2
3. EMITTER 1
4. COLLECTOR
5. COLLECTOR 2/BASE 1

STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 8:
PIN 1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. EMITTER

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42984B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	SC−88A (SC−70−5/SOT−353)	PAGE 1 OF 1

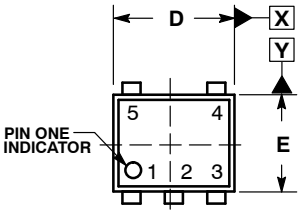
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

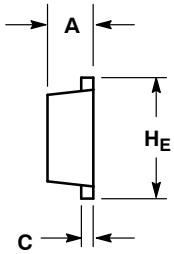
SOT−953
CASE 527AE
ISSUE E

DATE 02 AUG 2011

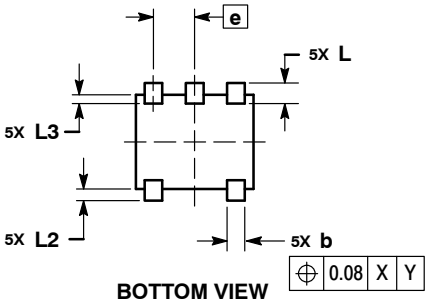
SCALE 4:1



TOP VIEW



SIDE VIEW

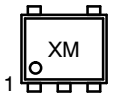


BOTTOM VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.10	0.15	0.20
C	0.07	0.12	0.17
D	0.95	1.00	1.05
E	0.75	0.80	0.85
e	0.35 BSC		
H_E	0.95	1.00	1.05
L	0.175 REF		
L2	0.05	0.10	0.15
L3	−−−	−−−	0.15

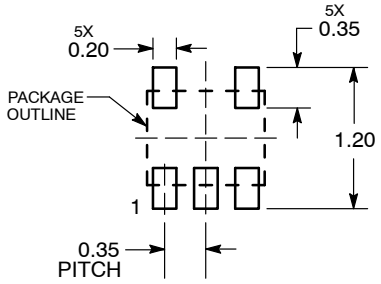
GENERIC MARKING DIAGRAM*



X = Specific Device Code
M = Month Code

*This information is generic. Please refer to device data sheet for actual part marking.
Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	**98AON26457D**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	**SOT−953**	**PAGE 1 OF 1**

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800−282−9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:
Phone: 00421 33 790 2910
For additional information, please contact your local Sales Representative

◊

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Buffers & Line Drivers ***category:***

Click to view products by ON Semiconductor ***manufacturer:***

Other Similar products are found below :

LXV200-024SW 74AUP2G34FW3-7 HEF4043BP PI74FCT3244L MC74HCT365ADTR2G Le87401NQC Le87402MQC 028192B 042140C 051117G 070519XB NL17SZ07P5T5G NLU1GT126AMUTCG 74AUP1G17FW5-7 74LVC2G17FW4-7 CD4502BE 5962-8982101PA 5962-9052201PA 74LVC1G125FW4-7 NL17SH17P5T5G NL17SH125P5T5G NLV37WZ07USG RHRXH162244K1 74AUP1G34FW5-7 74AUP1G07FW5-7 74LVC2G126RA3-7 NLX2G17CMUTCG 74LVCE1G125FZ4-7 Le87501NQC 74AUP1G126FW5-7 TC74HC4050AP(F) 74LVCE1G07FZ4-7 NLX3G16DMUTCG NLX2G06AMUTCG NLVVHC1G50DFT2G NLU2G17AMUTCG LE87100NQC LE87290YQC LE87290YQCT LE87511NQC LE87511NQCT LE87557NQC LE87557NQCT LE87614MQC LE87614MQCT 74AUP1G125FW5-7 NLU2G16CMUTCG MC74LCX244MN2TWG NLV74VHC125DTR2G NL17SG126DFT2G